## TOSHIBA TRANSISTOR SILICON NPN TRIPLE DIFFUSED MESA TYPE

# S2055N

## COLOR TV HORIZONTAL OUTPUT APPLICATIONS

• High Voltage : VCES = 1500 V

• Low Saturation Voltage :  $V_{CE (sat)} = 5 V (Max.)$ 

• High Speed :  $t_f = 0.3 \mu s$  (Typ.)

• Built-in Damper Type

• Collector Metal (Fin) is Fully Covered with Mold Resin.

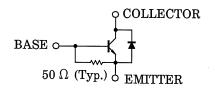
## MAXIMUM RATINGS (Tc = 25°C)

CHARACTERISTICS		SYMBOL	RATING	UNIT	
Collector-Emitter Voltage		V <sub>CES</sub>	1500	V	
Emitter-Base Voltage		V <sub>EBO</sub>	5	٧	
Collector Current	DC	I <sub>C</sub>	8	Α	
	Pulse	ICP	15	Α	
Base Current		lΒ	4	Α	
Collector Power Dissipation		PC	50	W	
Junction Temperature		Tj	150	°C	
Storage Temperature Range		T <sub>stg</sub>	-55~150	°C	
Thermal Resistance		R <sub>th (j-c)</sub>	2.5	°C/W	

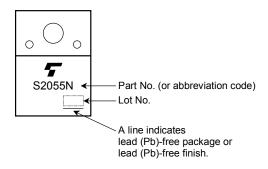
# Unit: mm 15.5±0.5 03.6±0.3 3.0±0.3 3.0±0.3 3.0±0.3 3.0±0.3 3.0±0.3 3.0±0.3 3.0±0.3 3.0±0.3 3.0±0.3 3.0±0.3 3.0±0.3 3.0±0.3 3.0±0.3 4.0 2.3MAX 0.95MAX 0.95M

Weight: 5.5 g (typ.)

## **EQUIVALENT CIRCUIT**



## **MARKING**



# **ELECTRICAL CHARACTERISTICS (Tc = 25°C)**

CHARACTERISTICS		SYMBOL	TEST CONDITION	MIN	TYP.	MAX	UNIT	
Collector Cut-off Current		I <sub>CBO</sub>	V <sub>CB</sub> = 1500 V, V <sub>BE</sub> = 0	_	_	1	mA	
Emitter-Base Breakdown Voltage		V (BR) EBO	I <sub>E</sub> = 0.4 A, I <sub>C</sub> = 0	5	_	_	V	
DC Current Gain		h <sub>FE (1)</sub>	V <sub>CE</sub> = 5 V, I <sub>C</sub> = 1 A	8	_	25		
		h <sub>FE (2)</sub>	V <sub>CE</sub> = 5 V, I <sub>C</sub> = 4.5 A	4.5	_	9		
Collector-Emitter Saturation Voltage		V <sub>CE (sat)</sub>	I <sub>C</sub> = 4.5 A, I <sub>B</sub> = 2 A	_	_	1	V	
			I <sub>C</sub> = 4.5 A, I <sub>B</sub> = 1 A	_	_	5		
Base-Emitter Satura	tion Voltage	V <sub>BE (sat)</sub>	I <sub>C</sub> = 4.5 A, I <sub>B</sub> = 1 A	_	0.9	1.2	V	
Forwardn Voltage(Da	amper Diode)	V <sub>F</sub>	I <sub>F</sub> = 6 A	_	1.6	2.0	V	
Collector-Emitter Sustain Voltage		V <sub>CEX</sub> (sus)	L = 40 mH, I <sub>C</sub> = 0.5A V <sub>BE</sub> = -1.7 V	700	_	_	V	
Transition Frequency		f <sub>T</sub>	V <sub>CE</sub> = 10 V, I <sub>C</sub> = 0.1 A	_	2	_	MHz	
Collector Output Capacitance		C <sub>ob</sub>	V <sub>CB</sub> = 10 V, I <sub>E</sub> = 0, f = 1 MHz	_	95	_	pF	
Switching Time (Fig. 1)	Storage Time	t <sub>stg</sub>	I <sub>CP</sub> = 4.5 A, I <sub>B1 (end)</sub> = 1 A f <sub>H</sub> = 15.75 kHz	_	7.5	11	- µs	
	Fall Time	t <sub>f</sub>		_	0.3	0.6		

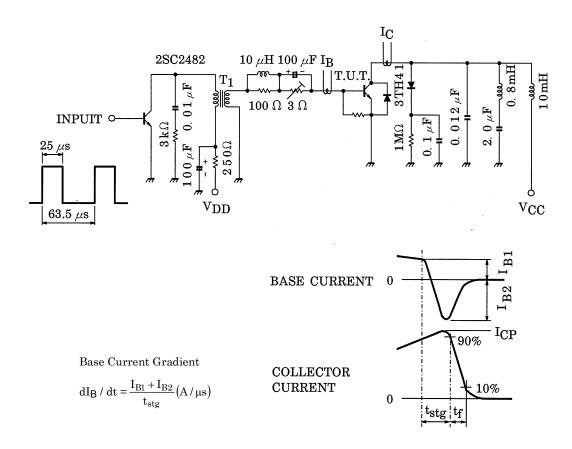
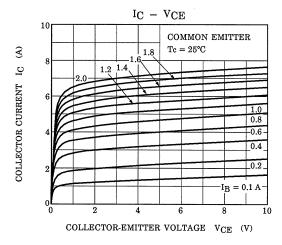
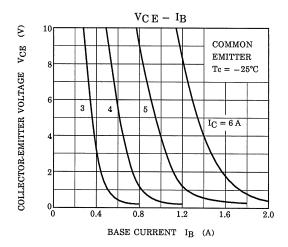
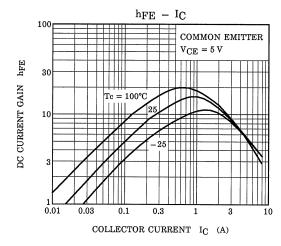


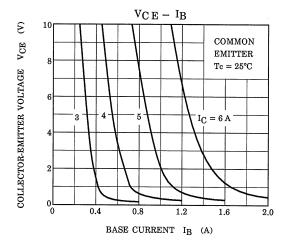
Fig. 1 SWITCHING TIME TEST CIRCUIT

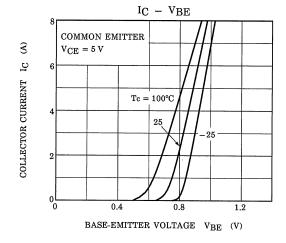
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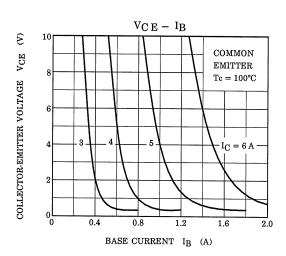


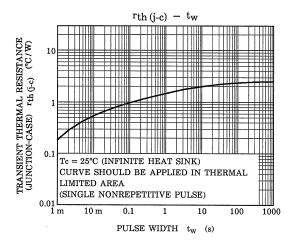


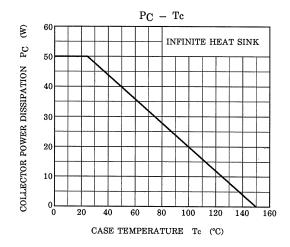


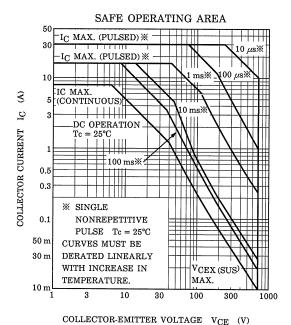












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